

HITJ0204MP

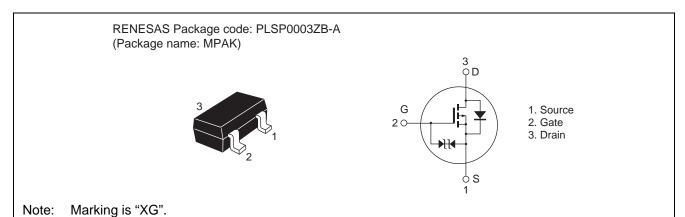
Silicon P Channel MOS FET Power Switching

R07DS0476EJ0100 Rev.1.00 Jun 22, 2011

Features

- Low on-resistance
 - $R_{\rm DS(on)}$ = 219 m Ω typ (V $_{\rm GS}$ = –4.5 V, I_D = –0.8 A)
- Low drive current
- High speed switching
- 2.5 V gate drive

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	-20	V
Gate to source voltage	V _{GSS}	+8 / -12	V
Drain current	I _D	-1.6	А
Drain peak current	I _{D(pulse)} Note1	-4.0	A
Body - drain diode reverse drain current	I _{DR}	-1.6	А
Channel dissipation	Pch Note2	0.8	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. When using the glass epoxy board (FR-4: 40 x 40 x 1 mm)

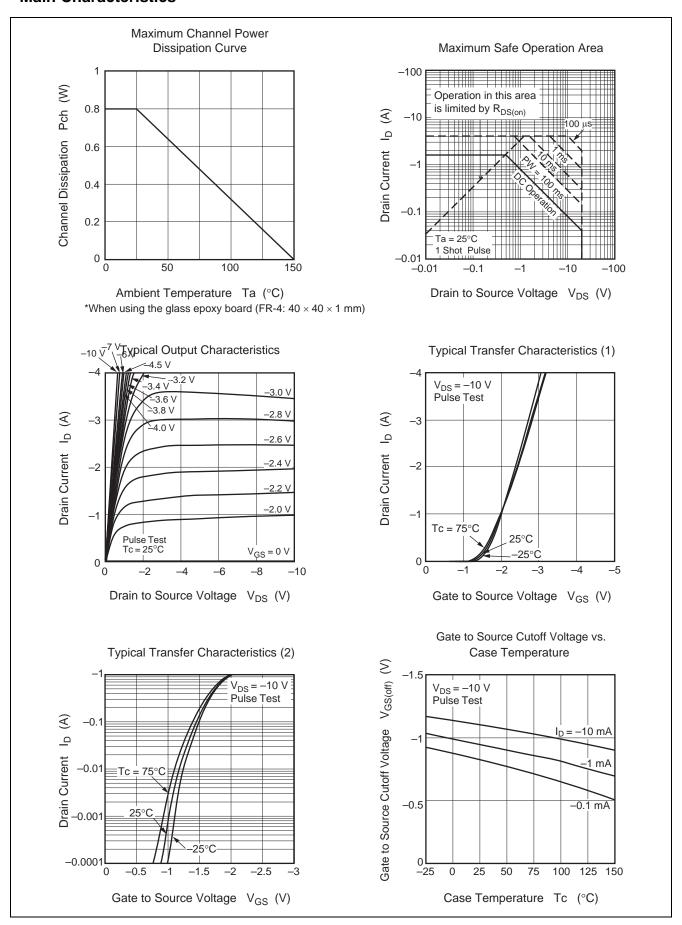
Electrical Characteristics

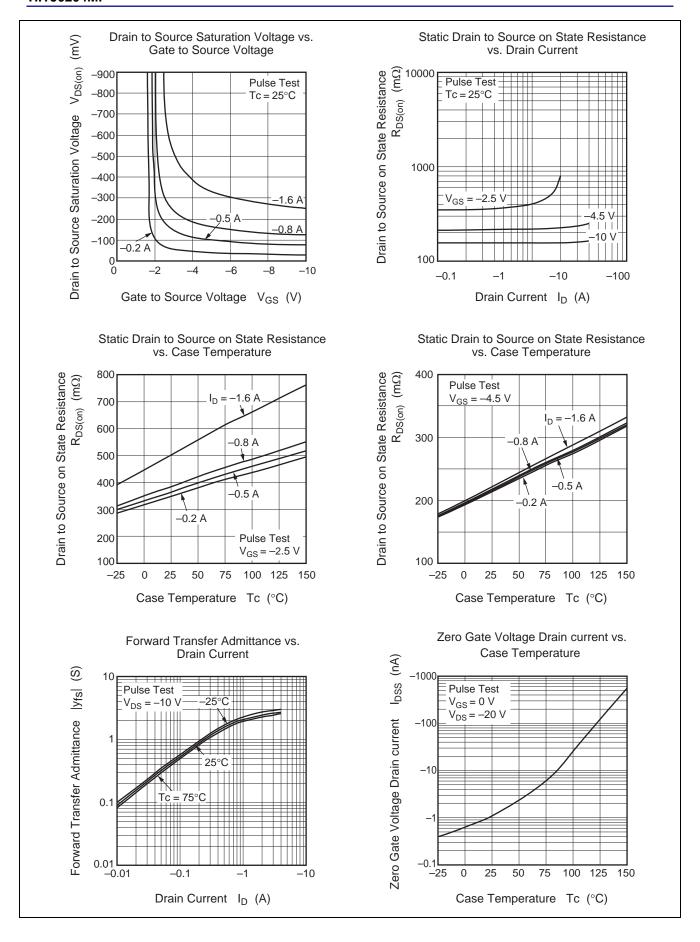
 $(Ta = 25^{\circ}C)$

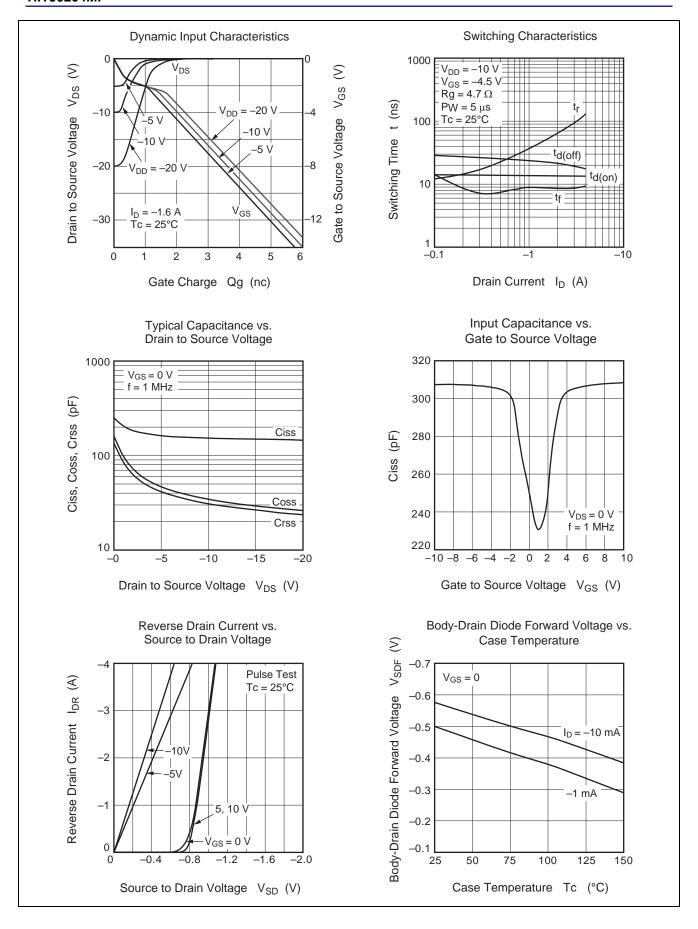
Item	Symbol	Min	Тур	Max	Unit	Test conditions	
Drain to source breakdown voltage	$V_{(BR)DSS}$	-20	_	_	V	$I_D = -10 \text{ mA}, V_{GS} = 0$	
Gate to source breakdown voltage	$V_{(BR)GSS}$	+8	_	_	V	$I_G = +100 \mu A, V_{DS} = 0$	
	V _{(BR)GSS}	-12		_	V	$I_G = -100 \mu A, V_{DS} = 0$	
Gate to source leak current	I _{GSS}			+10	μΑ	$V_{GS} = +6 \text{ V}, V_{DS} = 0$	
	I _{GSS}			-10	μΑ	$V_{GS} = -10 \text{ V}, V_{DS} = 0$	
Drain to source leak current	I _{DSS}			-1	μΑ	$V_{DS} = -20 \text{ V}, V_{GS} = 0$	
Gate to source cutoff voltage	$V_{GS(off)}$	-0.4		-1.4	V	$V_{DS} = -10 \text{ V}, I_D = -1 \text{ mA}$	
Drain to source on state resistance	R _{DS(on)}	_	219	280	mΩ	$I_D = -0.8 \text{ A}, V_{GS} = -4.5 \text{ V}^{\text{Note3}}$	
	R _{DS(on)}	_	363	510	mΩ	$I_D = -0.8 \text{ A}, V_{GS} = -2.5 \text{ V}^{\text{Note3}}$	
Forward transfer admittance	y _{fs}	1.3	1.9	_	S	$I_D = -0.8 \text{ A}, V_{DS} = -10 \text{ V}^{\text{Note3}}$	
Input capacitance	Ciss	_	153	_	pF	V _{DS} = −10 V	
Output capacitance	Coss	_	37	_	pF	$V_{GS} = 0$	
Reverse transfer capacitance	Crss	_	31	_	pF	f = 1 MHz	
Turn - on delay time	t _{d(on)}	_	14	_	ns	$I_D = -0.8 \text{ A}$	
Rise time	t _r	_	33	_	ns	$V_{GS} = -4.5 \text{ V}$ $R_L = 12.5 \Omega$ $Rg = 4.7 \Omega$	
Turn - off delay time	$t_{d(off)}$	_	24	_	ns		
Fall time	t _f	_	8	_	ns		
Total gate charge	Qg		2.2		nC	V _{DD} = -10 V	
Gate to source charge	Qgs		0.5		nC	$V_{GS} = -4.5 \text{ V}$	
Gate to drain charge	Qgd		0.9		nC	$I_D = -1.6A$	
Body - drain diode forward voltage	V_{DF}	_	-0.85	-1.1	V	$I_F = -1.6 \text{ A}, V_{GS} = 0^{\text{Note3}}$	

Notes: 3. Pulse test

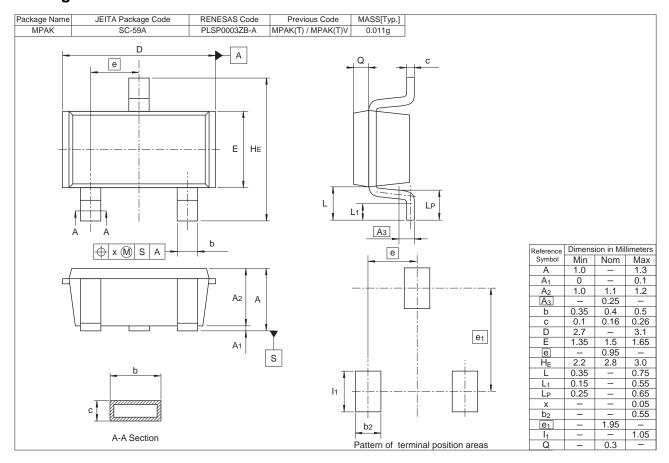
Main Characteristics







Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
HITJ0204MPTL-HQ	3000 pcs.	φ178 mm reel, 8 mm Emboss taping

Note: This product is designed for consumer use and not for automotive.

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